

# General imaging of advanced 3D mask objects based on the fully-vectorial Extended Nijboer-Zernike (ENZ) theory

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SPIE Advanced Lithography 2008, Optical Microlithography XXI  
San Jose, February 27th



# Contents

- Introduction to the ENZ-theory
- The ENZ-based imaging scheme
- Hopkins vs. ENZ
  - Periodicity
  - Mask topography effects
  - Significance of the on-axis field component
- Conclusions & Outlook

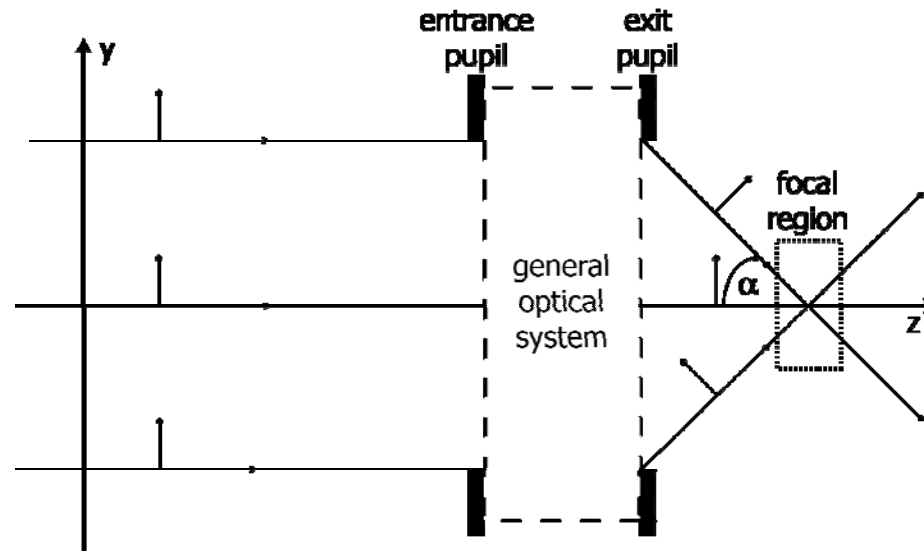
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# Introduction

## Extended Nijboer-Zernike theory

Semi-analytic solution to the Debye diffraction integral in case of a point-source at infinity.



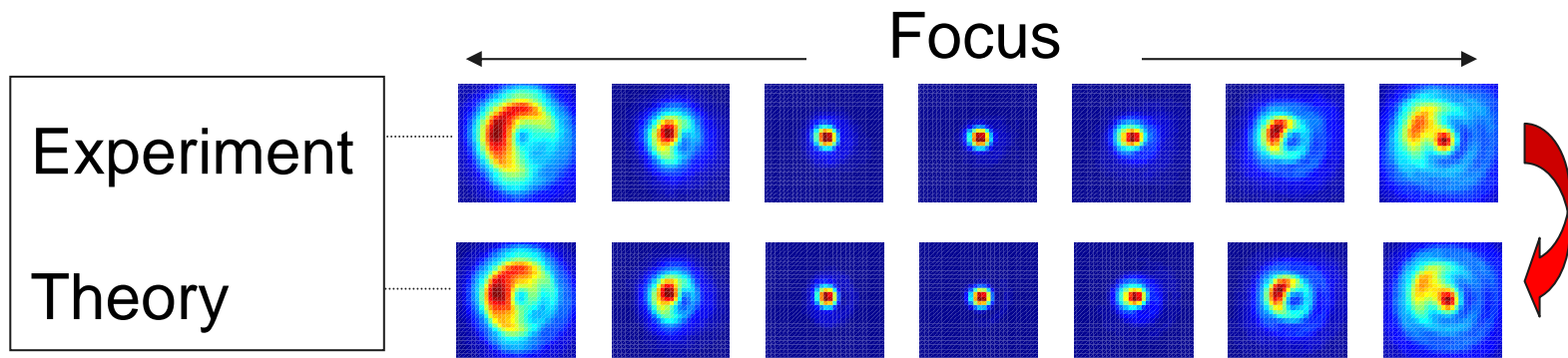
Exit pupil distribution  $\xrightarrow{\text{Debye}}$  Focal region (image)

# Introduction

## High quality optical system characterization

Observed Intensity = analytic expression  
 $\approx$  linearized analytic expression  
 $= \sum \beta(m,n) \times \text{basic-functions}$

Match experiment to theory:



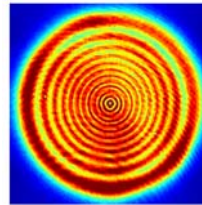
# Introduction

## ENZ historical overview

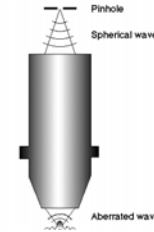
ENZ is born



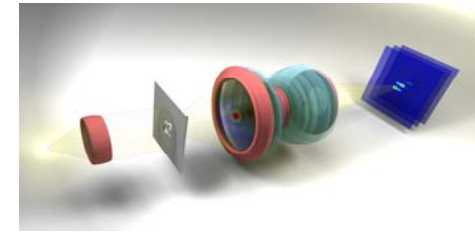
Arbitrary defocus



ENZ for lens metrology



ENZ-based imaging



1942

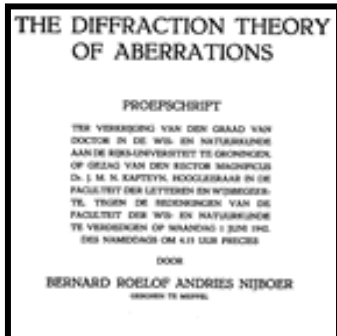
2000

2002

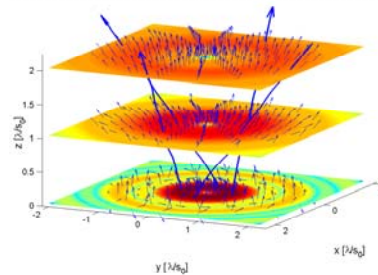
2004

2006

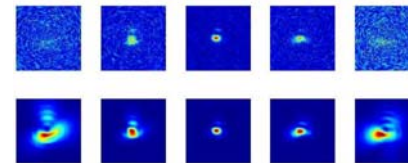
2008



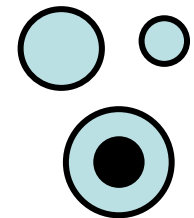
High-NA vector diffraction



General High-NA retrieval



Scaled, Annular pupils



June 17, 2008

6

# Introduction

## Main features of ENZ-theory

- Semi-analytic solution to the Debye diffraction integral based on a fast converging series expansion
- Highly accurate, typically  $10^{-6}$  in amplitude
- Both scalar and fully vectorial versions available
- Fast computations possible due to the use of basic functions that can be calculated and stored in advance
- Many focal planes can be calculated in a single computation

# Introduction

Question:

Can we exploit these ENZ-features for (mask) imaging?



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- Conclusions & Outlook

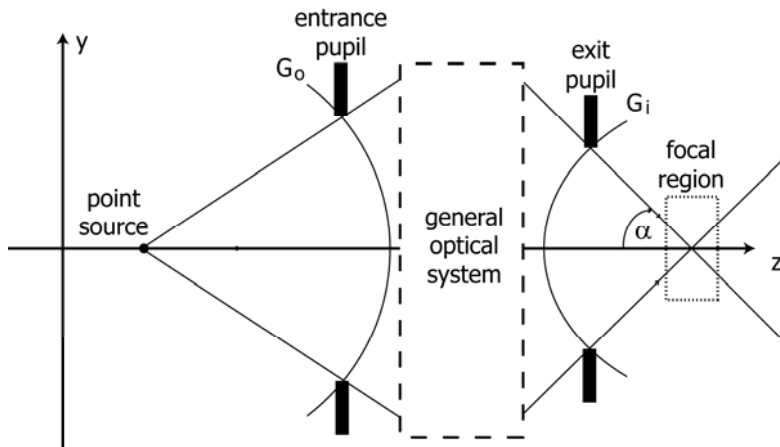
# ENZ-imaging

## Modifications to standard ENZ-formalism

- Allow objects at a **finite** distance

Characteristics:

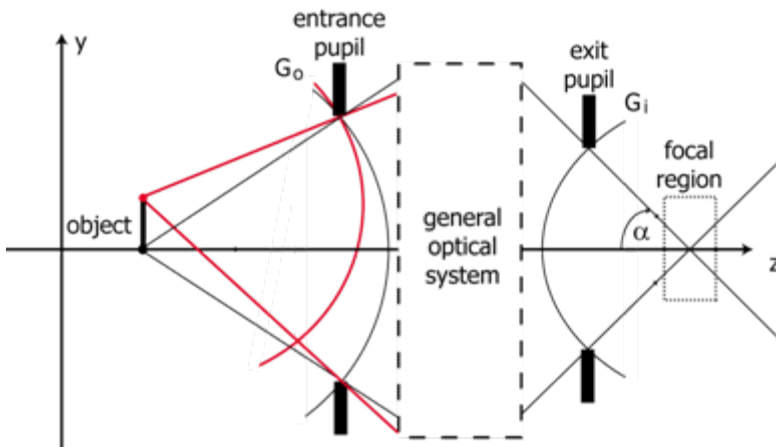
- Entrance pupil is a spherical surface  $G_0$



# ENZ-imaging

## Modifications to standard ENZ-formalism

- Allow objects at a **finite** distance
- Include **extended** objects



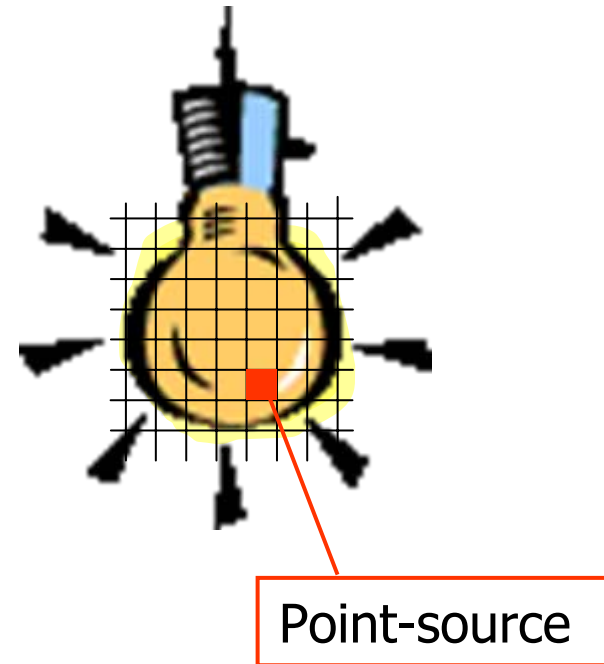
### Characteristics:

- Entrance pupil is a spherical surface  $G_0$
- In general a non-uniform field distribution on entrance pupil sphere
- Non-uniformity in the exit pupil results from non-uniformity in the entrance pupil and aberrations in the imaging system

# ENZ-imaging

## An Abbe-based computation scheme

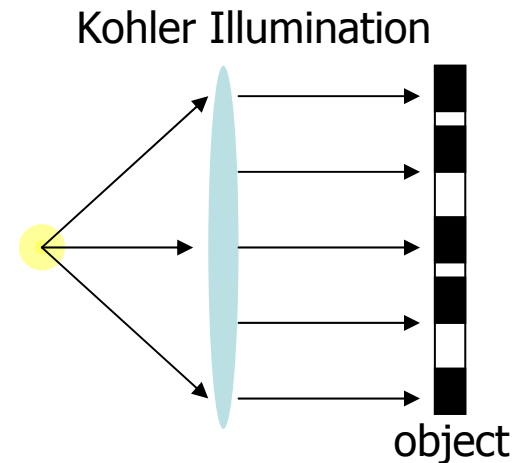
- Regard illumination source as superposition of point-sources



# ENZ-imaging

## An Abbe-based computation scheme

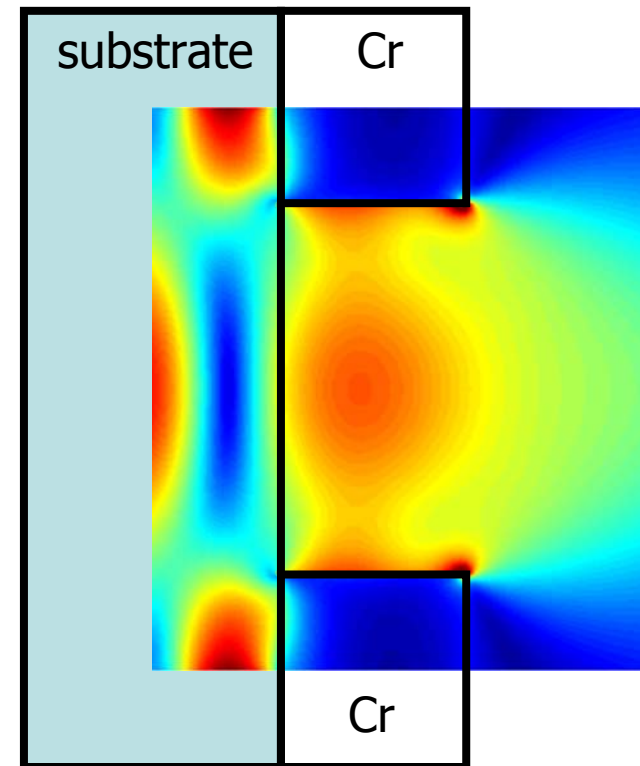
- Regard illumination source as superposition of point-sources
- A single point-source illuminates object with a plane wave



# ENZ-imaging

## An Abbe-based computation scheme

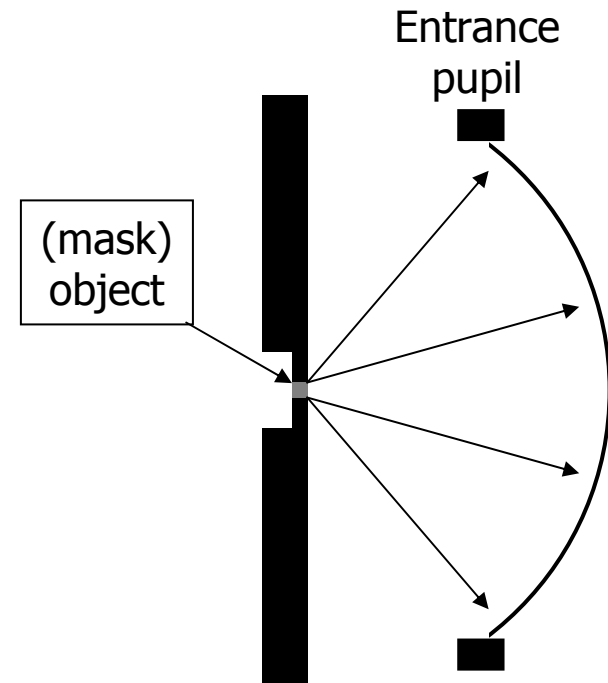
- Regard illumination source as superposition of point-sources
- A single point-source illuminates object with a plane wave
- Compute interaction between plane wave and (mask) object



# ENZ-imaging

## An Abbe-based computation scheme

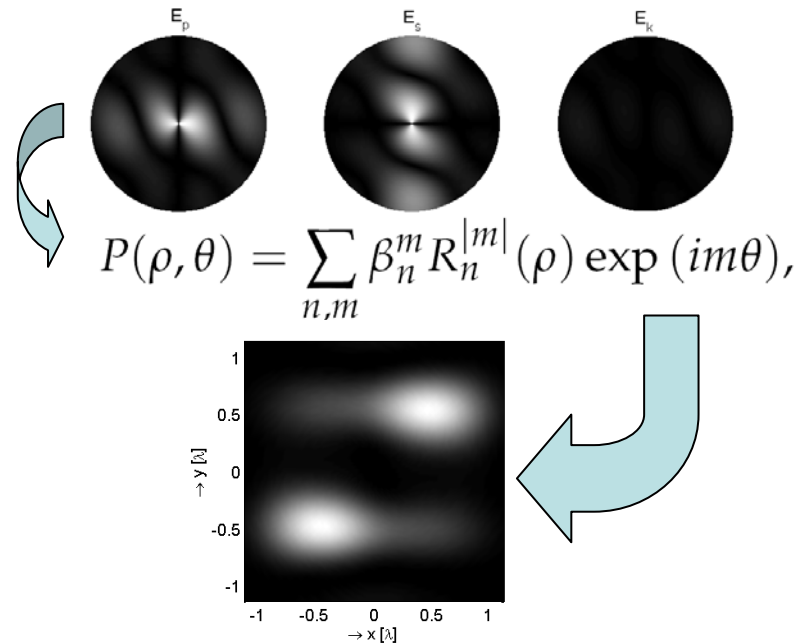
- Regard illumination source as superposition of point-sources
- A single point-source illuminates object with a plane wave
- Compute interaction between plane wave and (mask) object
- Propagate field to entrance pupil



# ENZ-imaging

## An Abbe-based computation scheme

- Regard illumination source as superposition of point-sources
- A single point-source illuminates object with a plane wave
- Compute interaction between plane wave and (mask) object
- Propagate field to entrance pupil
- Represent entrance pupil field in a Zernike expansion and use ENZ-theory to generate the image

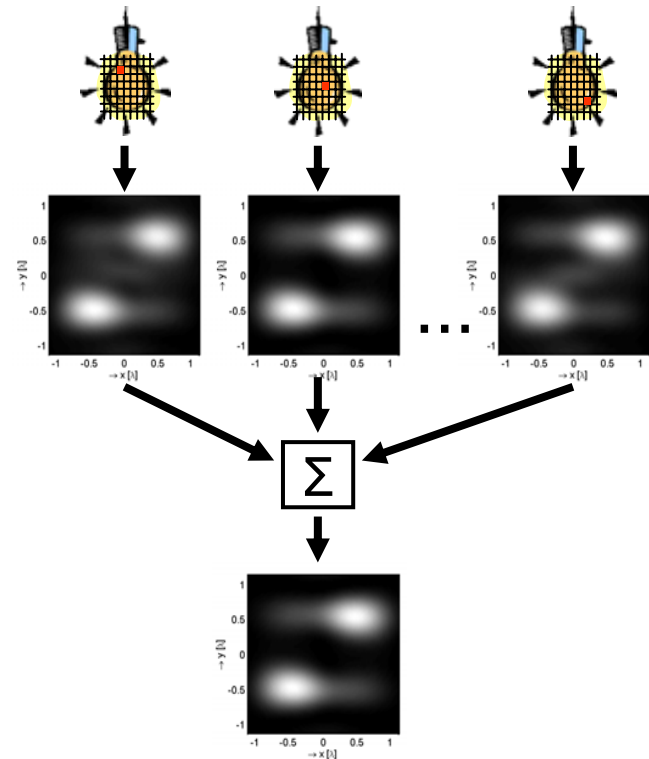




# ENZ-imaging

## An Abbe-based computation scheme

- Regard illumination source as superposition of point-sources
- A single point-source illuminates object with a plane wave
- Compute interaction between plane wave and (mask) object
- Propagate field to entrance pupil
- Represent entrance pupil field in a Zernike expansion and use ENZ-theory to generate the image
- Repeat for all source-points and sum incoherently



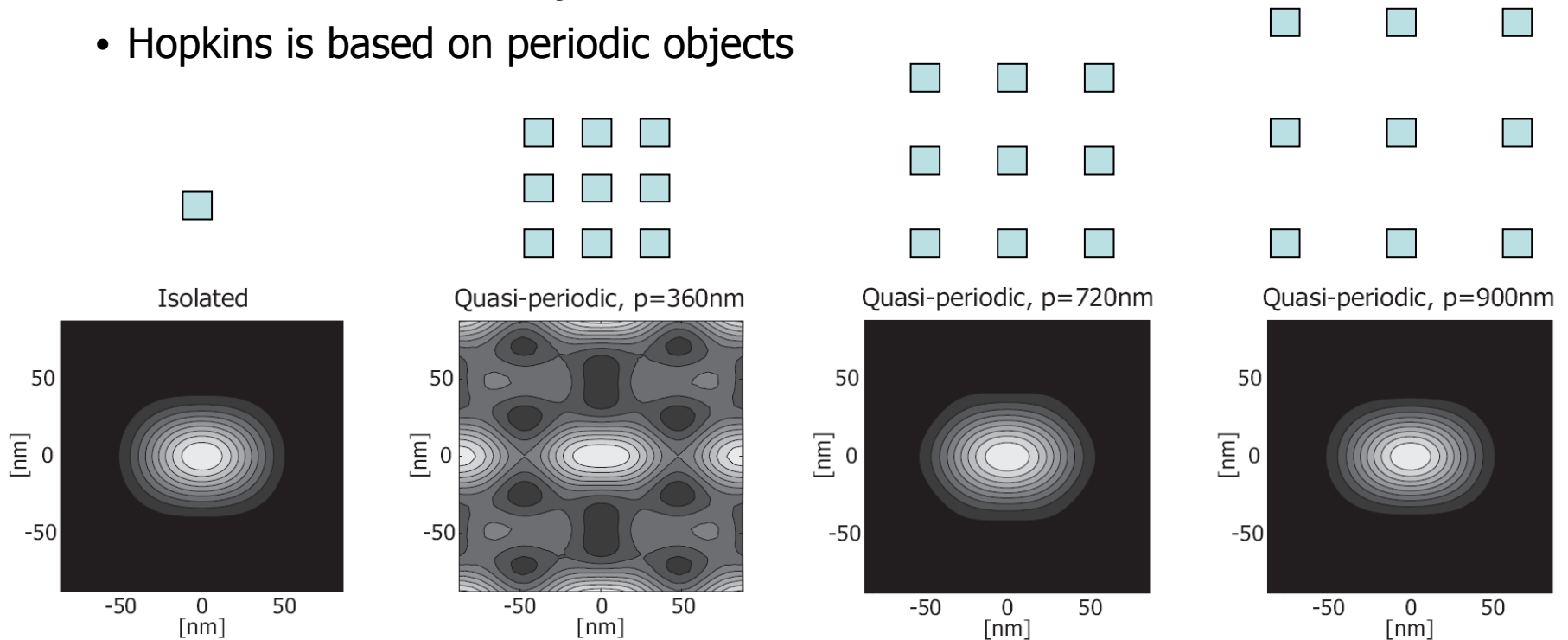
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# Hopkins vs. ENZ

## Periodicity

- ENZ acts on isolated objects
- Hopkins is based on periodic objects

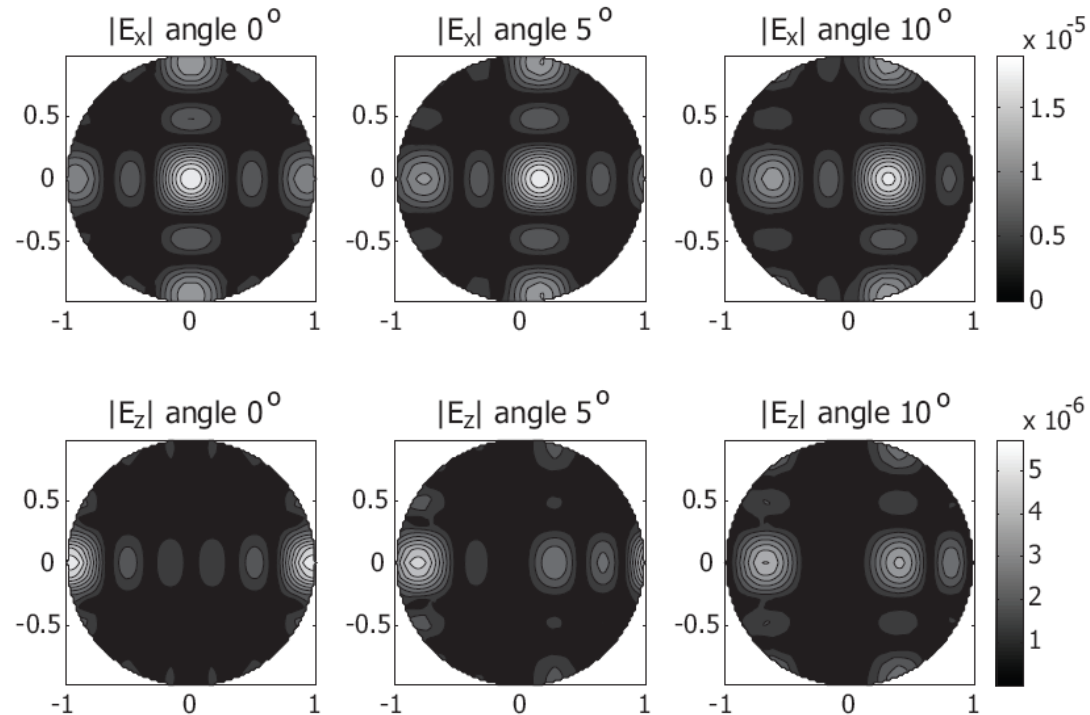


**Example: 180nm contact hole imaged with an immersion lithographic system  
(Reduction=4, NA=2.2,  $\lambda=193\text{nm}$ )**

# Hopkins vs. ENZ

## Mask topography effects

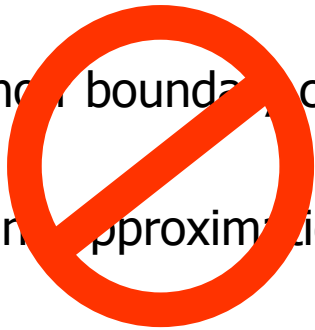
- Kirchhoff boundary conditions
- Hopkins approximation



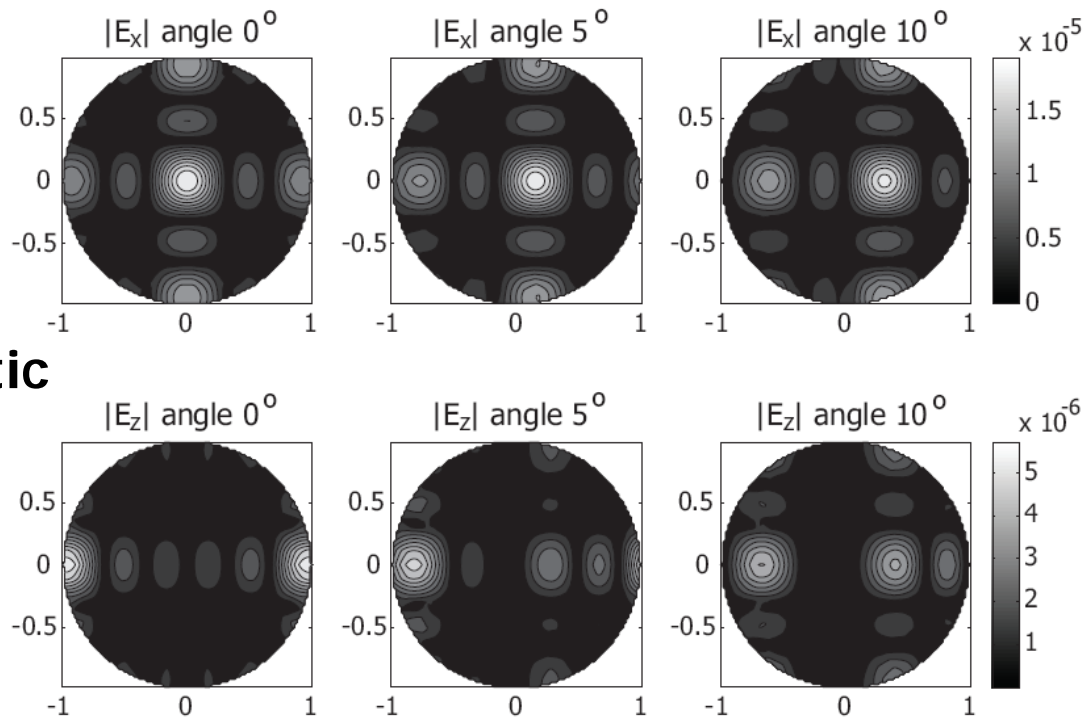
# Hopkins vs. ENZ

## Mask topography effects

- Kirchhoff boundary conditions
- Hopkins approximation



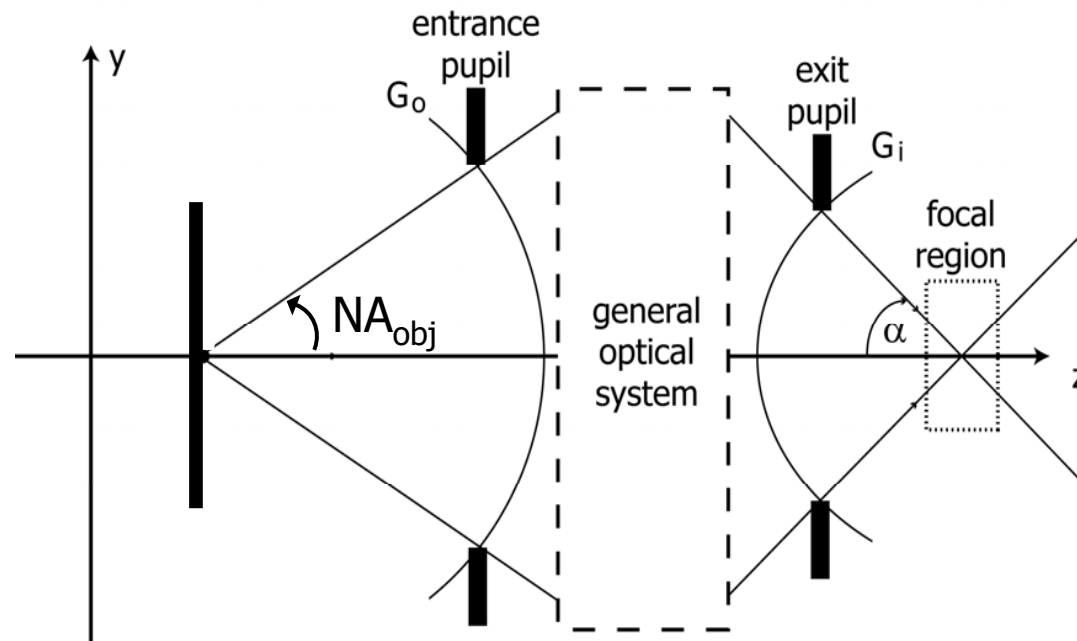
Present day advanced masks require electromagnetic treatment of the boundary value problem



# Hopkins vs. ENZ

## On-axis field component

- Object side NA can be relatively large ( $NA_{obj} > 0.2$ ) for lithographic immersion systems



# Hopkins vs. ENZ

## On-axis field component

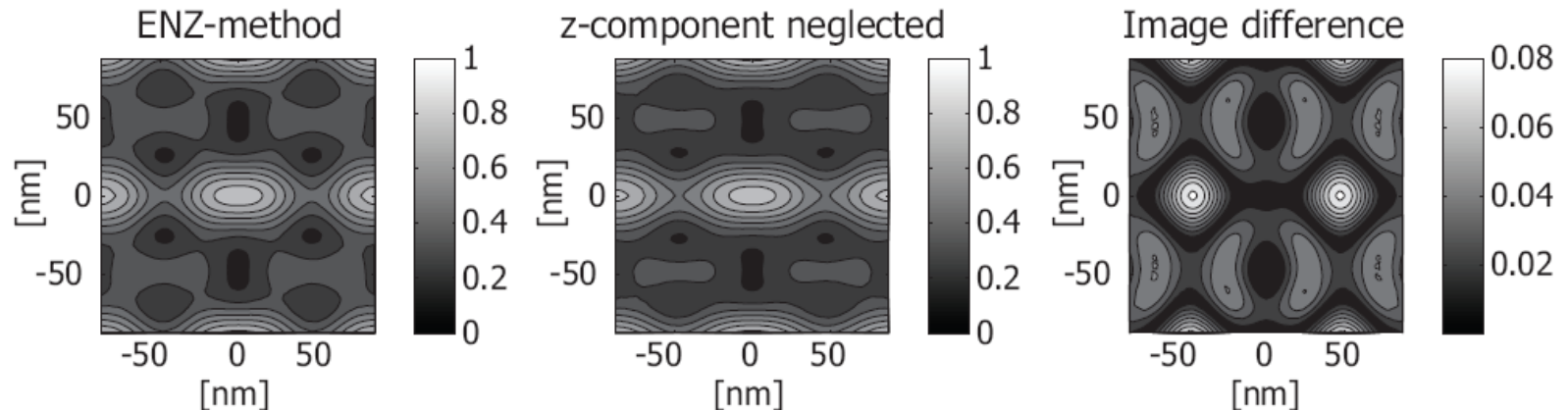
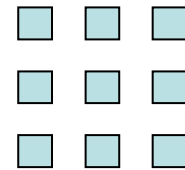
- Object side NA can be relatively large ( $NA_{\text{obj}} > 0.2$ ) for lithographic immersion systems
- In this regime the on-axis field component emerging from the (mask) object can give significant contributions to the image

# Hopkins vs. ENZ

## On-axis field component

- Object side NA can be relatively large ( $NA_{\text{obj}} > 0.2$ ) for lithographic immersion systems
- In this regime the on-axis field component emerging from the (mask) object can give significant contributions to the image

object



Example: array of 180nm contact holes imaged with an immersion lithographic system (Reduction=4,  $NA=2.2$ ,  $\lambda=193\text{nm}$ )



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- **Conclusions & Outlook**

# Conclusions & Outlook

- Abbe imaging method based on ENZ-theory
  - Naturally treats isolated structures
  - Relies on rigorous EM-solvers at the mask
  - Fully vectorial treatment
  - Potentially fast by the use of basic functions
  - Imaging in many focal planes at once
  - An independent method ideal for benchmarking purposes
- A more direct and accurate approach to lithographic simulations than Hopkins based methods

# Conclusions & Outlook

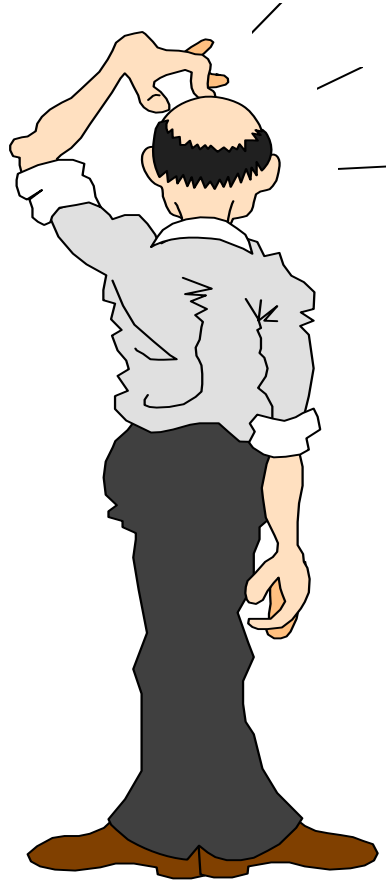
- Ongoing benchmark with existing methods
- Extension of the algorithm to include imaging in a multi-layer (resist)
- Further improve the computational efficiency:
  - coupling between EM-solver and ENZ-theory

Paper 6924-35:

Extended Nijboer-Zernike (ENZ) based mask imaging: efficient coupling of electromagnetic field solvers and the ENZ imaging algorithm

Time: 4:30 PM - 4:50 PM

# Questions?



<http://www.nijboerzernike.nl>